



U74AHCT3G06

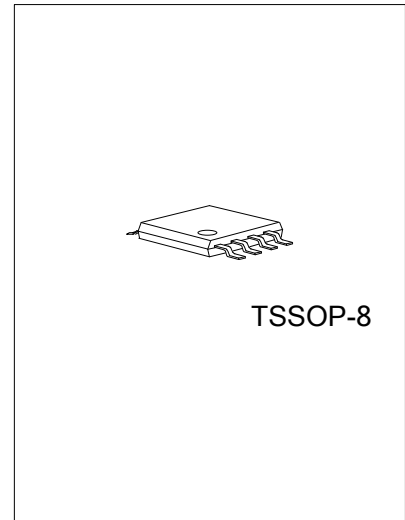
CMOS IC

INVERTER WITH OPEN-DRAIN OUTPUT

DESCRIPTION

The **U74AHCT3G06** is a high-speed Si-gate CMOS device which provides three inverting buffers with open-drain outputs. For digital operation this device must have a pull-up resistor to establish a logic HIGH-level.

The **U74AHCT3G06** is compatible of TTL input switching levels and has supply voltage range from 4.5V to 5.5V.



FEATURES

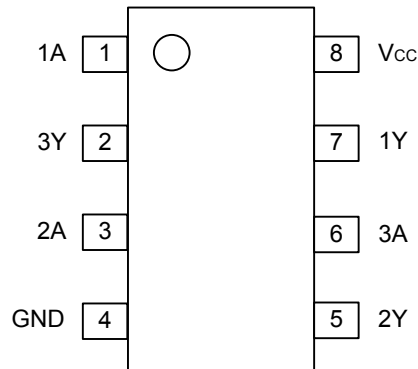
- * Low power supply 1.0µA at 5.5V
- * Up to 5.5V inputs accept voltages
- * Low power dissipation
- * Balanced propagation delays
- * High noise immunity
- * Output capability standard (open drain)

ORDERING INFORMATION

Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74AHCT3G06L-P08-R	U74AHCT3G06G-P08-R	TSSOP-8	Tape Reel
U74AHCT3G06L-P08-T	U74AHCT3G06G-P08-T	TSSOP-8	Tube

<p>U74AHCT3G06L-P08-R</p>	<p>(1)Packing Type (2)Package Type (3)Lead Free</p>	<p>(1) R: Tape Reel, T: Tube (2) P08: TSSOP-8 (3) G: Halogen Free, L: Lead Free</p>
---------------------------	---	---

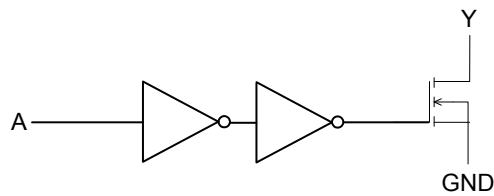
■ PIN CONFIGURATION



■ FUNCTION TABLE (each gate)

INPUT(A)	OUTPUT(Y)
L	Z
H	L

■ LOGIC DIAGRAM (each gate)



■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5 ~ 7.0	V
Input Voltage	V_{IN}	-0.5 ~ 7.0	V
Output Voltage	V_{OUT}	-0.5 ~ 7.0(active mode)	V
Output Voltage		-0.5 ~ 7.0(high-impedance mode)	V
V_{CC} or GND Current	I_{CC}	±75	mA
Output Current	I_{OUT}	±25	mA
Input Clamp Current	I_{IK}	-20	mA
Output Clamp Current	I_{OUT}	±20	mA
Operating Temperature	T_{OPR}	-40 ~ + 85	
Storage Temperature	T_{STG}	-65 ~ + 150	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
 Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		4.5	5.0	5.5	V
Input Voltage	V_{IN}		0		5.5	V
Output Voltage	V_{OUT}	Active mode	0		V_{CC}	V
		High-impedance mode	0		6.0	V
Input Rise or Fall Times	t_r, t_f	$V_{CC} = 5.0 \pm 0.5V$			20	ns/V

■ ELECTRICAL CHARACTERISTICS($T_A=25$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
High-Level Input Voltage	V_{IH}	$V_{CC} = 4.5 V$ to $5.5 V$	2.0			V	
Low-Level Input Voltage	V_{IL}	$V_{CC} = 4.5 V$ to $5.5 V$			0.8	V	
Low-Level Output Voltage	V_{OL}	$V_{CC} = 4.5V,$ $V_I = V_{IH}$ or V_{IL}	$I_O = 50 \mu A$		0	0.1	V
			$I_O = 8.0 mA$			0.36	
Input Leakage Current	$I_{I(LEAK)}$	$V_I = 5.5V$ or GND, $V_{CC} = 0V$ to $5.5V$			0.1	μA	
3-State output OFF-State Current	I_{OZ}	$V_{CC} = 5.5V, V_I = V_{IH}$ or $V_{IL}, V_O = V_{CC}$ or GND			±.025	μA	
Quiescent Supply Current	I_{CC}	$V_{CC} = 5.5V, V_I = V_{CC}$ or GND, $I_O = 0$			1.0	μA	
Additional Quiescent Supply Current	ΔI_{CC}	$V_{CC} = 5.5V,$ One input at $3.4V,$ Other inputs at V_{CC} or GND, $I_{OUT} = 0$			1.35	mA	
Input Capacitance	C_{IN}	$V_I = V_{CC}$ or GND		1.5	10	pF	

■ SWITCHING CHARACTERISTICS ($T_A=25^\circ\text{C}$, $t_R = t_F \leq 3.0\text{ ns}$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Propagation Delay from Input (A) to Output(Y)	t_{PZL}	$V_{CC} 4.5V \text{ to } 5.5V$	$C_L 15pF$	-	3.0	5.3	ns
	t_{PLZ}			-	3.2	4.6	
	t_{PZL}		$C_L 50pF$	-	4.2	7.5	ns
	t_{PLZ}			-	4.5	7.0	

■ OPERATING CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	TYP	UNIT
Power Dissipation Capacitance	C_{PD}	$C_L=50pF, f=1MHz$ (Note1, 2)	4.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

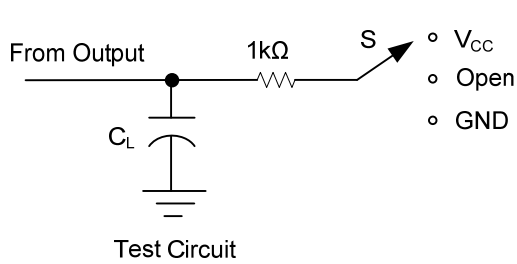
V_{CC} = supply voltage in Volts;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

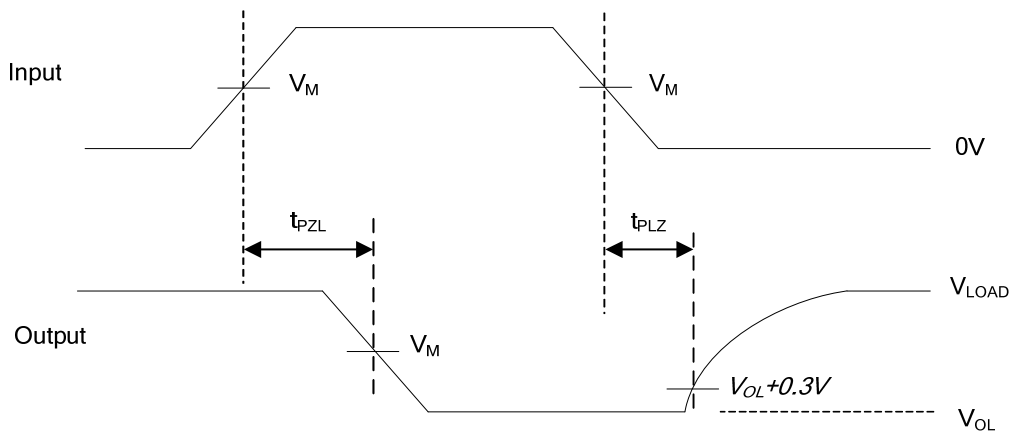
2. The condition is $V_I = GND$ to V_{CC} .

TEST CIRCUIT AND WAVEFORMS



TEST	S
t _{PLH} /t _{PHL}	Open
t _{PHZ} /t _{PZH}	GND
t _{PLZ} /t _{PZL}	V _{CC}

V _I	V _M	V _M
GND to V _{CC}	50%V _{CC}	50%V _{CC}



Voltage Waveforms Enable and Disable Times

Note: C_L includes probe and jig capacitance.
 P_{RR} ≤ 1MHz, Z_O = 50Ω, t_r ≤ 3ns, t_f ≤ 3ns.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.